Ordering number : EN5914

CMOSIC



LC75396NE

Single-Chip Electronic Volume Control System



Overview

The LC75396NE is an electronic volume control system providing control over volume, balance, 5-band equalizer, and input switching based on serial inputs.

Functions

• Volume control:

The chip provides 81 levels of volume attenuation: in 1-dB step between 0 dB and -79 dB and $-\infty$.

Independent control over left front/rear and right front/rear channels provides balance control.

• Equalizer:

The chip provides control in 2-dB steps over the range between +10 dB and -10 dB. Four of the five bands have peaking equalization; the remaining one, shelving equalization.

• Selector:

The left and right channels each offer a choice of five inputs. The L5 and R5 inputs can be turned on and off independently. An external constant determines the amplification for the input signal.

- · Serial data input
 - Supports CCB* format communication with the system controller.

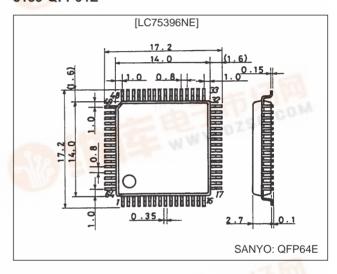
Features

- Built-in buffer amplifiers reduce the number of external parts required.
- Silicon gate CMOS process reduces the noise of built-in switch.
- V_{DD}/2 reference voltage generation circuit built in.

Package Dimensions

unit: mm

3159-QFP64E



- CCB is a trademark of SANYO ELECTRIC CO., LTD.
- CCB is SANYO's original bus format and all the bus addresses are controlled by SANYO.

Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$, $V_{SS} = 0$ V

Parameter Sym		Conditions	Ratings	Unit
Maximum supply voltage	V _{DD} max	V _{DD}	11	V
Maximum input voltage	V _{IN} max	CL, DI, CE, L1 to L5, R1 to R5, LTIN, RTIN, LFIN, RFIN, LRIN, RRIN	$V_{SS} - 0.3 \text{ to} $ $V_{DD} + 0.3$	V
Allowable power dissipation	Pd max	Ta ≤ 75°C, with PC board	550	mW
Operating temperature	Topr		-30 to +75	°C
Storage temperature	Tstg		-40 to +125	°C

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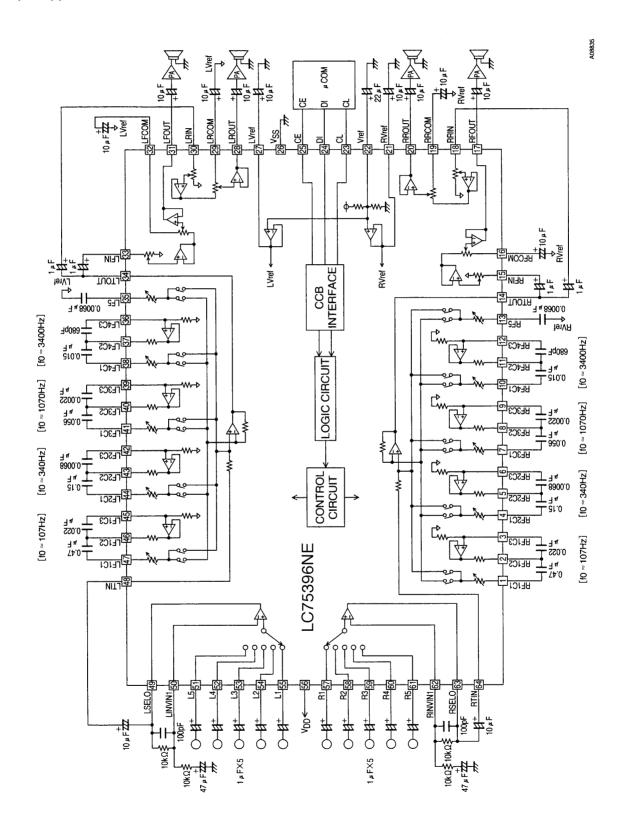
Allowable Operating Ranges at $Ta=-30\ to+75^{\circ}C,\,V_{SS}=0\ V$

Parameter	Symbol	nbol Conditions		Ratings			
Farameter	Symbol	Conditions	min	typ	max	Unit	
Supply voltage	V _{DD}	V _{DD}	6.0		10.5	V	
Input high level voltage	V _{IH}	CL, DI, CE	4.0		V _{DD}	V	
Input low level voltage	V _{IL}	CL, DI, CE	V _{SS}		1.0	V	
Input voltage amplitude	V _{IN}	CL, DI, CE, L1 to L5, R1 to R5, LTIN, RTIN, LFIN, RFIN, LRIN, RRIN	V _{SS}		V _{DD}	Vp-p	
Input pulse width	t _{øW}	CL	1.0			μs	
Setup time	t _{SETUP}	CL, DI, CE	1.0			μs	
Hold time	t _{HOLD}	CL, DI, CE	1.0			μs	
Operating frequency	fopg	CL			500	kHz	

Electrical Characteristics at $Ta=25^{\circ}C,\,V_{DD}=10~V,\,V_{SS}=0~V$

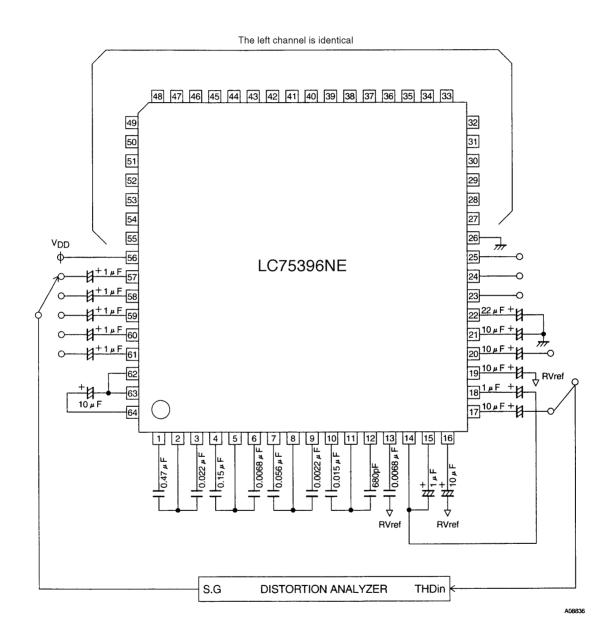
Parameter	Cumphal	mbol Conditions -		Ratings			
Parameter	Symbol			typ	max	Unit	
[Input block]	•				•		
Input resistance	Rin	L1 to L5, R1 to R5		50		kΩ	
Clipping level	Vcl	LSELO, RSELO: THD = 1.0%		3.00		Vrms	
Output load resistance	R _L	LSELO, RSELO	10			kΩ	
[Volume control block]					•		
Input resistance	Rin	LFIN, LRIN, RFIN, RRIN		100		kΩ	
[Equalizer control block]							
Control range	Geq	Max, boost/cut	±8	±10	±12	dB	
Step resolution	Estep		1	2	3	dB	
Internal feedback resistance	Rfeed		17	28	39	kΩ	
[Overall characteristics]	•				•	•	
Total harmonic distortion	THD	V _{IN} = 1 Vrms, f = 1 kHz, with all controls flat overall			0.01	%	
Crosstalk	СТ	V_{IN} = 1 Vrms, f = 1 kHz, with all controls flat overall, Rg = 1 k Ω	80			dB	
Output noise voltage	V _N 1	With all controls flat overall, BW = 20 to 20kHz		2.9		μV	
Output Hoise voltage	V _N 2	GEQ F1 Band = +10dB, With all controls overall, BW = 20 to 20kHz		17		μV	
Output at maximum attenuation	V _O min	V _{IN} = 1 Vrms, f = 1 kHz, main volume -∞		-90		dB	
Current drain	I _{DD}	V _{DD} – V _{SS} = 10.5 V		46.5	55.8	mA	
Input high level current	I _{IH}	CL, DI, CE, V _{IN} = 10.5 V			10	μA	
Input low level current	IIL	CL, DI, CE, V _{IN} = 0 V	-10			μA	

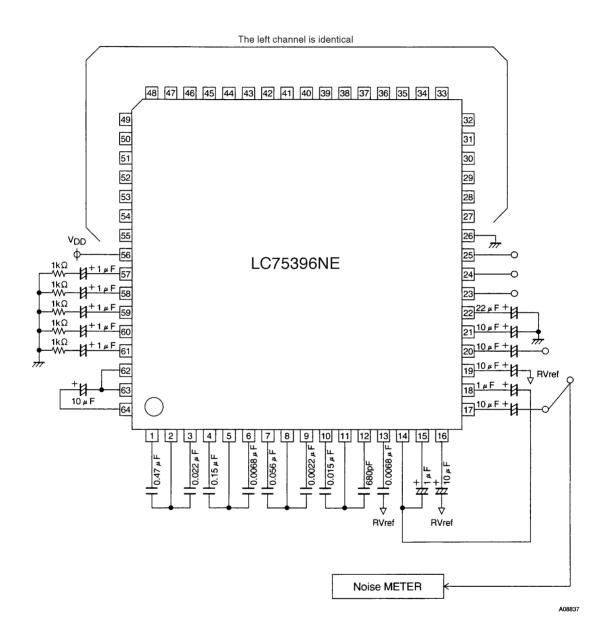
Sample Application Circuit



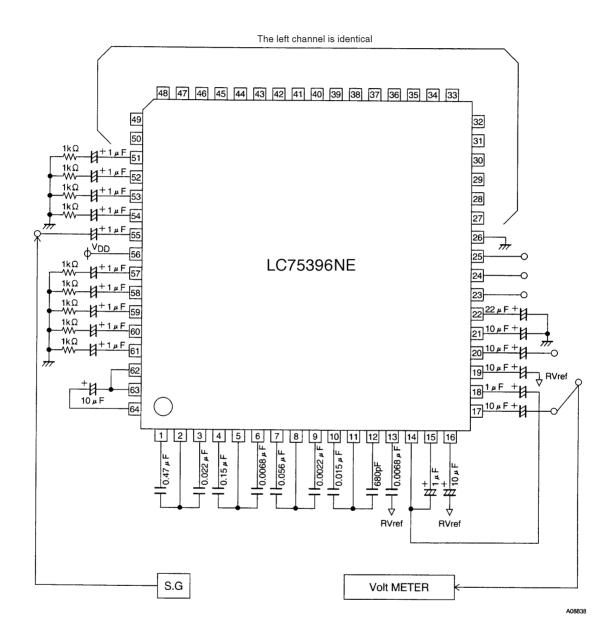
Test Circuits

Total Harmonic Distortion

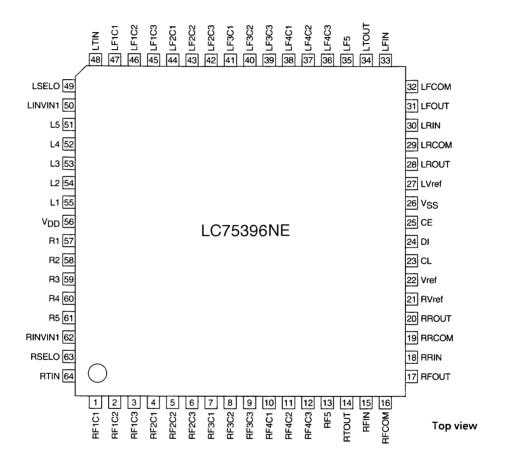




Crosstalk



Pin Assignment



A08839

Pin Functions

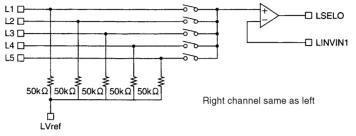
Pin No.	Pin	Function	Equivalent circuit
55	L1		
54	L2		Ŷ V _{DD}
53	L3		
52	L4		1
51	L5		
57	R1	Signal inputs	
58	R2		
59	R3		INVIN1 Vref
60	R4		A08840
61	R5		0.1/0.0
			VDD ↓
50	LINVIN1	Inverting inputs to the operational amplifier that sets the input	
62	RINVIN1	gain	
			777 A08841
			9.Vpp
			INVIN1
49	LSELO	Input selector outputs	
63	RSELO	1	
			Vref A08842
			O VTEI A08842
			\$\frac{1}{4}\triangle \text{DD}
48	LTIN	Equalizer inputs	
64	RTIN	Equalizatinputa	_
			7777 A08843
47	LF1C1		
46	LF1C2	Connections for the capacitors that form the equalizer F1	
45	LF1C3	band filters	γV _{DD}
1	RF1C1	Capacitors must be connected between:	——W———□ FnC1
2	RF1C2	LF1C1 (RF1C1) and LF1C2 (RF1C2), and between	*** ** ** ** ** **
3	RF1C3	LF1C2 (RF1C2) and LF1C3 (RF1C3).	<i>m</i>
3	KI 103		₹ ºVDD
44	LF2C1	Commentions for the comment was that forms the commelling FO	↑ ★ □V40
43	LF2C2	Connections for the capacitors that form the equalizer F2 band filters	→ Uvref2
42	LF2C3	Capacitors must be connected between:	
4	RF2C1	LF2C1 (RF2C1) and LF2C2 (RF2C2), and between	٩٧ _{DD}
5	RF2C2		
6	RF2C3	LF2C2 (RF2C2) and LF2C3 (RF2C3).	FnC2
41	LF3C1		↑ ↑
		· Connections for the capacitors that form the equalizer F3	
40	LF3C2	band filters	
39	LF3C3	Capacitors must be connected between:	
7	RF3C1	LF3C1 (RF3C1) and LF3C2 (RF3C2), and between	FnC3
8	RF3C2	LF3C2 (RF3C2) and LF3C3 (RF3C3).	
9	RF3C3		/// °, V _{DD}
38	LF4C1	Connections for the connections that forms the same it	👗
37	LF4C2	Connections for the capacitors that form the equalizer F4 band filters	─────────────────────────────────────
	LF4C3	Capacitors must be connected between:	,
36		Capacitors must be connected between.	1
36 10	RF4C1	LEAC1 (DEAC1) and LEAC2 (DEAC2) and hatman	A08844
	RF4C1 RF4C2	LF4C1 (RF4C1) and LF4C2 (RF4C2), and between LF4C2 (RF4C2) and LF4C3 (RF4C3).	AU6944

Continued from preceding page.

Pin No.	Pin	Function	Equivalent circuit
35 13	LF5 RF5	Connections for the capacitors that form the equalizer F5 band filters Connections for external capacitors	A08845
33 30 15 18 32 29	LFIN LRIN RFIN RRIN LFCOM	 Input to the left channel front 4-dB step volume control. Input to the left channel rear 4-dB step volume control. Input to the right channel front 4-dB step volume control. Input to the right channel rear 4-dB step volume control. Common pin for the left channel front 1-dB step volume control. Common pin for the left channel rear 1-dB step volume control. 	VDD → VDD → A08846
16 19	RFCOM RRCOM	Common pin for the right channel front 1-dB step volume control. Common pin for the right channel rear 1-dB step volume control.	
31 28 17 20	LFOUT LROUT RFOUT RROUT	Left channel front volume control output Left channel rear volume control output Right channel front volume control output Right channel rear volume control output	A08847
34 14	LTOUT RTOUT	Equalizer outputs	AO8848
22	Vref	 A capacitor of a few tens of μF must be inserted between Vref and AV_{SS} (V_{SS}) to handle power supply ripple in the V_{DD}/2 voltage generation circuit. 	Vref MA08949
27 21	LVref RVref	Internal analog system grounds	Vref A08850
56	V _{DD}	Power supply	
26	V _{SS}	• Ground	
25	CE	Chip enable When this pin goes from high to low, data is written to an internal latch and the analog switches operate. Data transfers are enabled when this pin is at the high level.	Z Z
24 23	DI CL	Serial data and clock inputs for chip control.	A08851

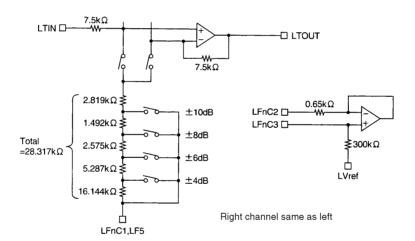
Equivalent Circuit Diagram

Selector Control Block



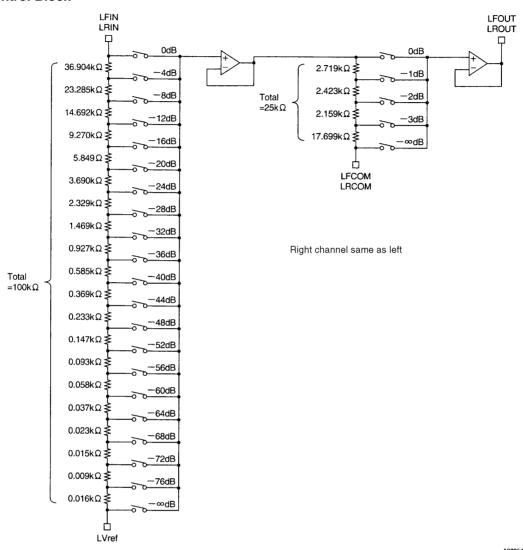
A08852

Equalizer Control Block



A08853

Volume Control Block

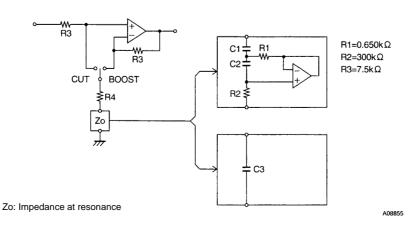


Calculating the Size of External Capacitors

The LC75396NE supports four bands with peaking characteristics and one band with shelving characteristics

- 1. Peaking Characteristics (bands F1 to F4)

 The external capacitor functions as the structural element of a simulated inductor. The equivalent circuit and the calculations required to achieve the desired center frequency are shown below.
 - Equivalent circuit for the simulated inductor



• Calculation example

Specifications: Central frequency, $F_O = 107 \text{ Hz}$

Q factor at maximum boost, $Q_{+10 \text{ dB}} = 0.8$

— Calculate Q₀, the sharpness of the simulated inductance itself.

$$Q_O = (R1 + R4)/R1 \times Q_{+10dB}$$

Note: R4 is from the separately issued internal block diagram.

— Calculate C1

$$C1 = 1/2\pi F_{O}R1Q_{O} \neq 0.536~(\mu F)$$

— Calculate C2

$$C2 = Q_0/2\pi F_0 R2 \neq 0.021 (\mu F)$$

· Sample results

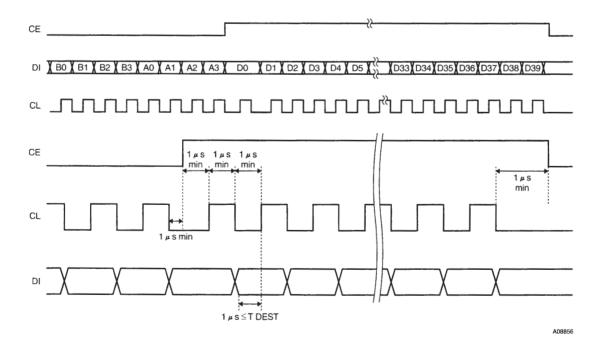
Central frequency F _O (Hz)	C1 (F)	C2 (F)
107	0.536 μ	0.021 μ
340	0.169 μ	6663 _P
1070	0.054 μ	2117 _P
3400	0.017 μ	666 _P

2. Shelving characteristics (Band F5)

Achieving the desired control of 2-dB steps over the range between +10 dB to -10 dB requires choosing a capacitor, C3, with an impedance of 650 Ω .

Control System Timing and Data Formats

To control the LC75396NE, specified sequences are required to be input through the pins CE, CL, and DI. Each sequence consists of 48 bits: an 8-bit address followed by 40 bits of data.



1. Address Code (B0 to A3)

This product uses an 8-bit address code, and supports the same specifications as other Sanyo CCB serial bus products.

Address code (LSB)

В0	B1	B2	В3	A0	A1	A2	A3	
0	1	0	0	0	0	0	1	(82HEX)

2. Control Code Allocations

Input switching control

D0	D1	D2	Operation		
0	0	0	L1 (R1)	ON	
1	0	0	L2 (R2)	ON	
0	1	0	L3 (R3)	ON	
1	1	0	L4 (R4)	ON	
0	0	1		OFF	
1	0	1		OFF	
0	1	1		OFF	
1	1	1		OFF	

Input switching control

D3	Operation				
0	L5 (R5)	OFF			
1	L5 (R5)	ON			

Five band equalizer control

D4	D5	D6	D7	Band f1
D8	D9	D10	D11	Band f2
D12	D13	D14	D15	Band f3
D16	D17	D18	D19	Band f4
D20	D21	D22	D23	Band f5
1	0	1	0	+10dB
0	0	1	0	+8dB
1	1	0	0	+6dB
0	1	0	0	+4dB
1	0	0	0	+2dB
0	0	0	0	0dB
1	0	0	1	-2dB
0	1	0	1	-4dB
1	1	0	1	-6dB
0	0	1	1	-8dB
1	0	1	1	-10dB

Volume control

D24	D25	D26	D27	D28	D29	D30	D31	Operation
								1dB STEP
0	0							0dB
1	0							-1dB
0	1							-2dB
1	1							−3dB
								4dB STEP
		0	0	0	0	0	0	0dB
		1	0	0	0	0	0	-4dB
		0	1	0	0	0	0	-8dB
		1	1	0	0	0	0	-12dB
		0	0	1	0	0	0	-16dB
		1	0	1	0	0	0	-20dB
		0	1	1	0	0	0	-24dB
		1	1	1	0	0	0	-28dB
		0	0	0	1	0	0	-32dB
		1	0	0	1	0	0	-36dB
		0	1	0	1	0	0	-40dB
		1	1	0	1	0	0	-44dB
		0	0	1	1	0	0	-48dB
		1	0	1	1	0	0	-52dB
		0	1	1	1	0	0	-56dB
		1	1	1	1	0	0	-60dB
		0	0	0	0	1	0	-64dB
		1	0	0	0	1	0	-68dB
		0	1	0	0	1	0	-72dB
		1	1	0	0	1	0	-76dB
								MUTE
		1	1	1	1	1	0	-∞

Channel selection control

D32	D33	Operation
0	0	Initial setting
1	0	RCH
0	1	LCH
1	1	Simulataneous left and right

Left channel volume rear/front control

D34	Operation			
0	Rear			
1	Front			

Control is enabled when D33 = 1

Right channel volume rear/front control

D35	Operation		
0	Rear		
1	Front		

Control is enabled when D32 = 1

Test mode control

D36	D37	D38	D39	Operation
0	0	0	0	These bits are for chip testing and must all be set to 0 in application systems.

Notes: After power is first applied, applications must initialize this chip by sending the initial data (1) and (2) described below.

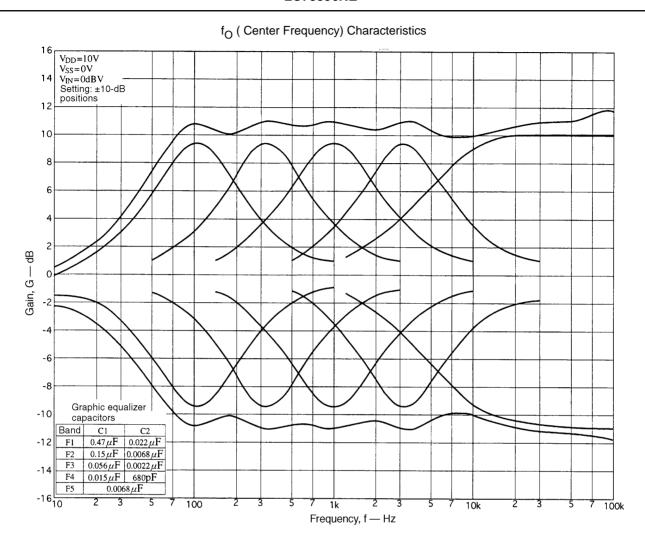
Initial data ... (1) Address 01000001

Data: (Set the volume to −∞set both D34 and D35 to 1, and set all other data to 0)

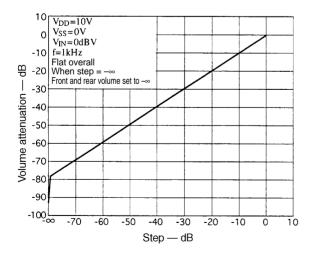
(2) Address 01000001

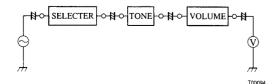
Data: (Set the volume to $-\infty$, set both D34 and D35 to 0, and set all other data to 0)

After transferring that data, set the left and right channel initial settings before turning off the mute function.

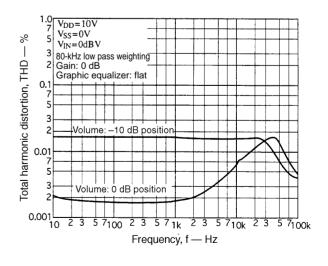


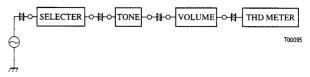
Volume Step Characteristics

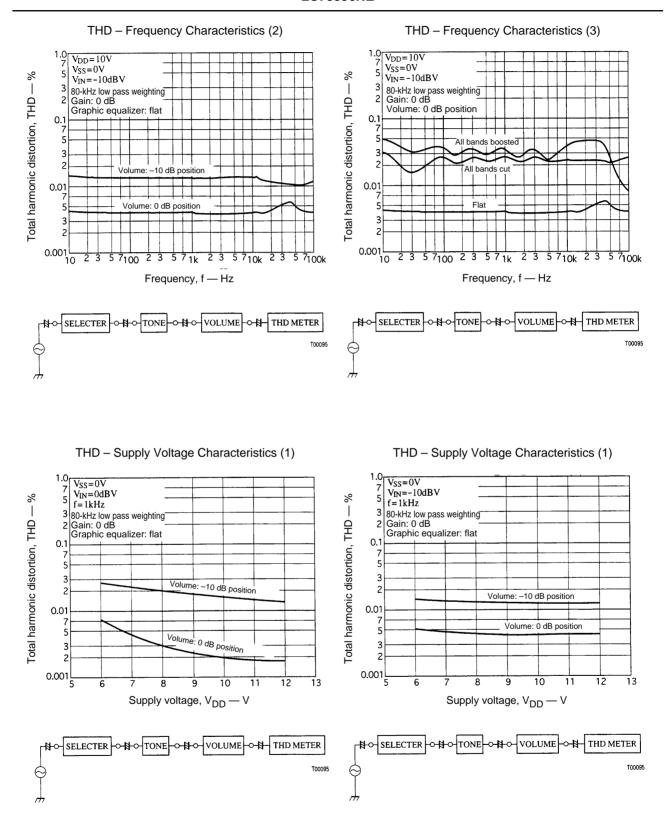


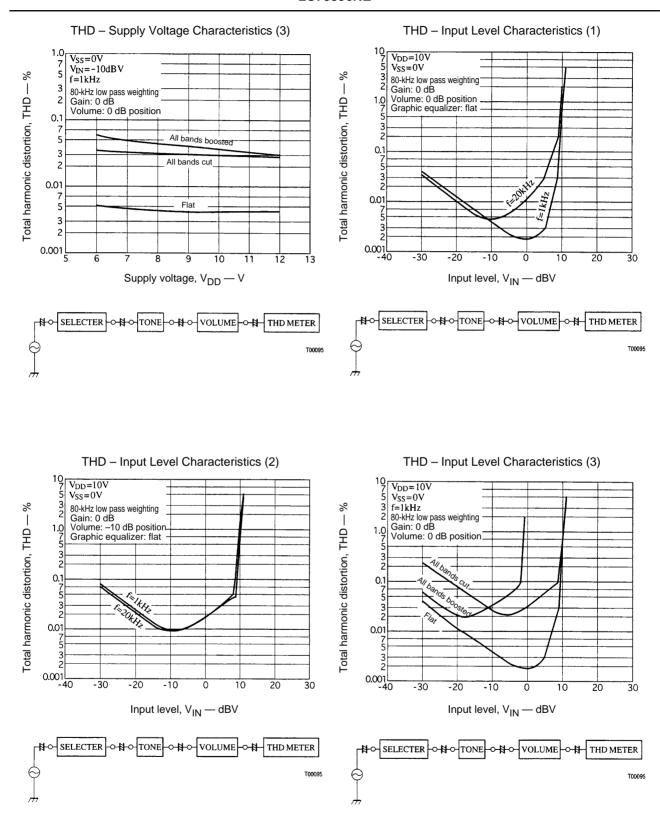


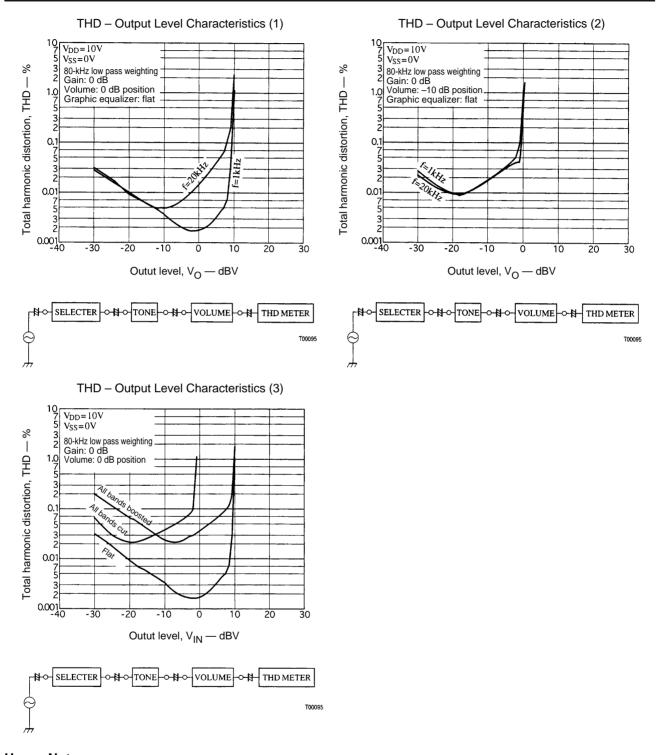
THD - Frequency Characteristics (1)











Usage Notes

- When the power is first applied, the internal analog switches are in indeterminate states. The chip therefore requires muting or other external measures until it has received the proper data.
- After power is first applied, applications must initialize this chip by sending the initial data (1) and (2) described below.

Initial data ...

(1) Address 01000001

Data: (Set the volume to $-\infty$, set both D34 and D35 to 0, and set all other data to 0)

(2) Address 01000001

Data: (Set the volume to $-\infty$, set both D34 and D35 to 1, and set all other data to 0)

After transferring that data, set the left and right channel initial settings before turning off the mute function.

• Provide grounding patterns or shielding for the lines to the CL, DI, and CE pins so as to prevent their high-frequency digital signals from interfering with the operation of nearby analog circuits.

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